2SD2598

Silicon NPN epitaxial planer type darlington

For low-frequency amplification

Features

- Forward current transfer ratio h_{FE} is designed high, which is appropriate to the driver circuit of motors and printer bammer: h_{FE} = 4000 to 20000.
- A shunt resistor is omitted from the driver.
- M type package allowing easy automatic and manual insertion as well as stand-alone fixing to the printed circuit board.

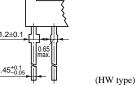
Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	60	V
Collector to emitter voltage	V _{CEO}	50	V
Emitter to base voltage	V _{EBO}	5	V
Peak collector current	I _{CP}	750	mA
Collector current	I_{C}	500	mA
Collector power dissipation	P _C *1	1	W
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	−55 ~ +150	°C

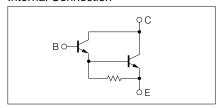
^{*} Printed circuit board: Copper foil area of 1cm² or more, and the board thickness of 1.7mm for the collector portion

Note: In addition to the lead type shown in the lower figure, the type as shown in the lower figure is also available.

also available.



Internal Connection



Electrical Characteristics (Ta=25°C)

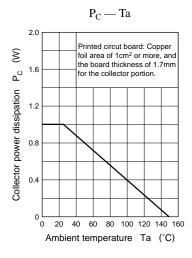
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 25V, I_{E} = 0$			100	nA
Emitter cutoff current	I _{EBO}	$V_{EB} = 4V, I_{C} = 0$			100	nA
Collector to base voltage	V _{CBO}	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$	60			V
Collector to emitter voltage	V _{CEO}	$I_C = 1 \text{mA}, I_B = 0$	50			V
Emitter to base voltage	V _{EBO}	$I_E = 100 \mu A, I_C = 0$	5			V
Forward current transfer ratio	h _{FE} *1	$V_{CE} = 10V, I_C = 500 \text{mA}^{*2}$	4000		20000	
Collector to emitter saturation voltage	V _{CE(sat)}	$I_C = 500 \text{mA}, I_B = 0.5 \text{mA}^{*2}$			2.5	V
Base to emitter saturation voltage	V _{BE(sat)}	$I_C = 500 \text{mA}, I_B = 0.5 \text{mA}^{*2}$			3.0	V
Transition frequency	f_{T}	$V_{CB} = 10V, I_E = -50mA, f = 200MHz$		200		MHz

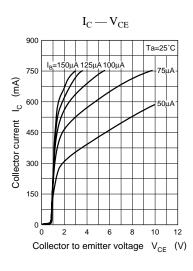
^{*1}hFE Rank classification

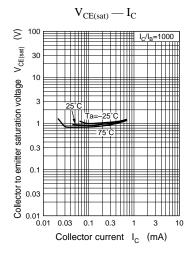
Rank	Q	R		
h_{FE}	4000 ~ 10000	8000 ~ 20000		

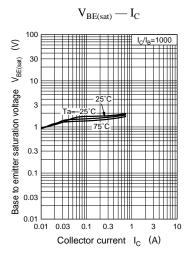
*2 Pulse measurement

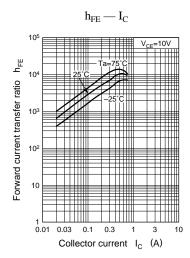
Transistor 2SD2598

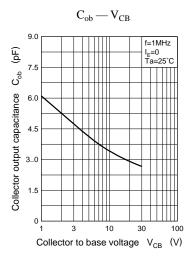












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